

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	371	349/141	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2002/05/3 0 10:15
2	BRS	L2	96	1 and silicon adj oxide	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2002/05/3 0 10:38
3	BRS	L3	62	2 and gate adj insulat\$	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2002/05/3 0 10:40